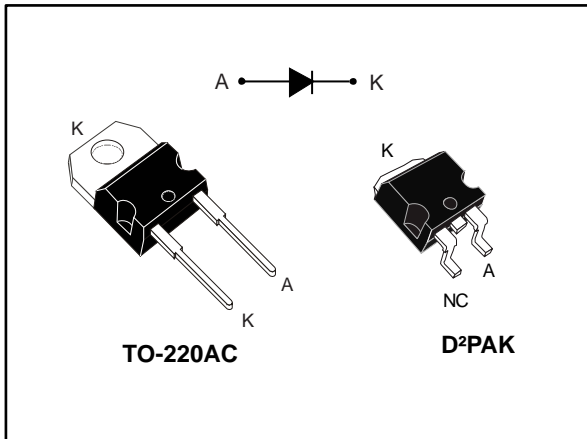


## 1200 V power Schottky silicon carbide diode

Datasheet - production data



### Description

The SiC diode, available in TO-220AC and D<sup>2</sup>PAK, is an ultrahigh performance power Schottky rectifier. It is manufactured using a silicon carbide substrate. The wide band-gap material allows the design of a low  $V_F$  Schottky diode structure with a 1200 V rating. Due to the Schottky construction, no recovery is shown at turn-off and ringing patterns are negligible. The minimal capacitive turn-off behavior is independent of temperature.

Especially suited for use in PFC and secondary side applications, this ST SiC diode will boost the performance in hard switching conditions. This rectifier will enhance the performance of the targeted application. Its high forward surge capability ensures a good robustness during transient phases.

### Features

- No or negligible reverse recovery
- Switching behavior independent of temperature
- Robust high voltage periphery
- ECOPACK<sup>®</sup>2 compliant

Table 1: Device summary

Symbol	Value
$I_{F(AV)}$	20 A
$V_{RRM}$	1200 V
$T_j$ (max.)	175 °C
$V_F$ (typ.)	1.35 V

# 1 Characteristics

**Table 2: Absolute ratings (limiting values at 25 °C, unless otherwise specified)**

Symbol	Parameter		Value	Unit	
V <sub>RRM</sub>	Repetitive peak reverse voltage (T <sub>j</sub> = -40 °C to +175 °C)		1200	V	
I <sub>F(RMS)</sub>	Forward rms current		38	A	
I <sub>F(AV)</sub>	Average forward current	T <sub>c</sub> = 155 °C, DC current	20	A	
I <sub>FRM</sub>	Repetitive peak forward current	T <sub>c</sub> = 155 °C, T <sub>j</sub> = 175 °C, δ = 0.1	78	A	
I <sub>FSM</sub>	Surge non repetitive forward current	t <sub>p</sub> = 10 ms sinusoidal	T <sub>c</sub> = 25 °C	140	A
			T <sub>c</sub> = 150 °C	120	
		t <sub>p</sub> = 10 μs square	T <sub>c</sub> = 25 °C	700	
T <sub>stg</sub>	Storage temperature range		-65 to +175	°C	
T <sub>j</sub>	Operating junction temperature		-40 to +175	°C	

**Table 3: Thermal parameters**

Symbol	Parameter	Typ. value	Max. value	Unit
R <sub>th(j-c)</sub>	Junction to case	0.30	0.45	°C/W

**Table 4: Static electrical characteristics**

Symbol	Parameter	Test conditions		Min.	Typ.	Max.	Unit
I <sub>R</sub> <sup>(1)</sup>	Reverse leakage current	T <sub>j</sub> = 25 °C	V <sub>R</sub> = V <sub>RRM</sub>	-	10	120	μA
		T <sub>j</sub> = 150 °C		-	60	800	
V <sub>F</sub> <sup>(2)</sup>	Forward voltage drop	T <sub>j</sub> = 25 °C	I <sub>F</sub> = 20 A	-	1.35	1.50	V
		T <sub>j</sub> = 150 °C		-	1.75	2.25	

**Notes:**

<sup>(1)</sup>Pulse test: t<sub>p</sub> = 10 ms, δ < 2%

<sup>(2)</sup>Pulse test: t<sub>p</sub> = 500 μs, δ < 2%

To evaluate the conduction losses use the following equation:

$$P = 1.07 \times I_{F(AV)} + 0.059 \times I_{F(RMS)}^2$$

**Table 5: Dynamic electrical characteristics**

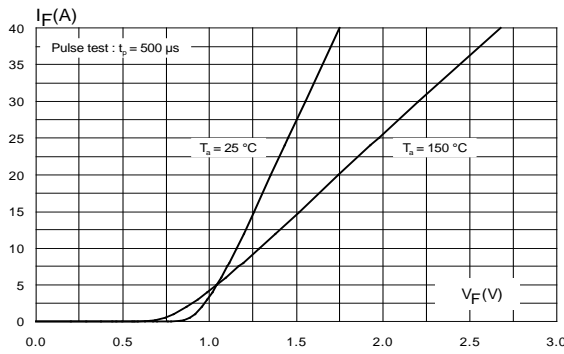
Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
Q <sub>Cj</sub> <sup>(1)</sup>	Total capacitive charge	V <sub>R</sub> = 800 V	-	129	-	nC
C <sub>j</sub>	Total capacitance	V <sub>R</sub> = 0 V, T <sub>c</sub> = 25 °C, F = 1 MHz	-	1650	-	pF
		V <sub>R</sub> = 800 V, T <sub>c</sub> = 25 °C, F = 1 MHz	-	110	-	

**Notes:**

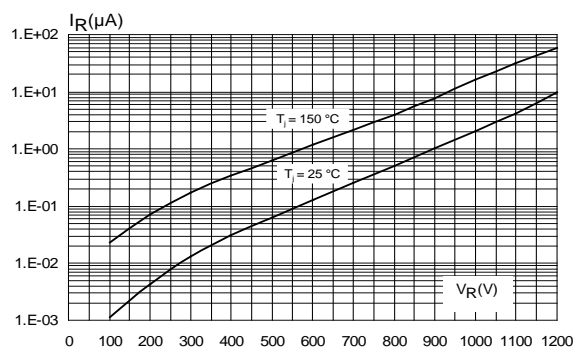
<sup>(1)</sup>Most accurate value for the capacitive charge:  $Q_{Cj}(V_R) = \int_0^{V_R} C_j(V) dV$

# 1.1 Characteristics (curves)

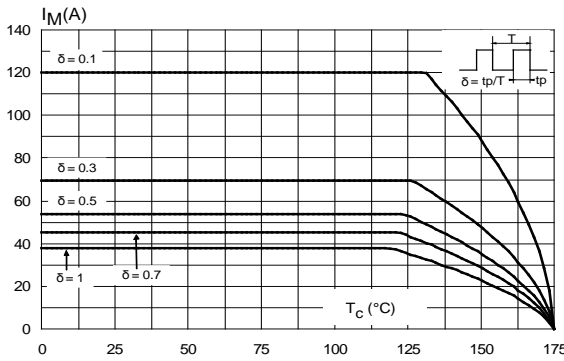
**Figure 1: Forward voltage drop versus forward current (typical values)**



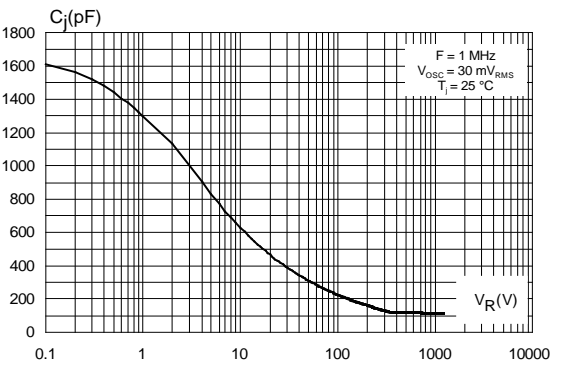
**Figure 2: Reverse leakage current versus reverse voltage applied (typical values)**



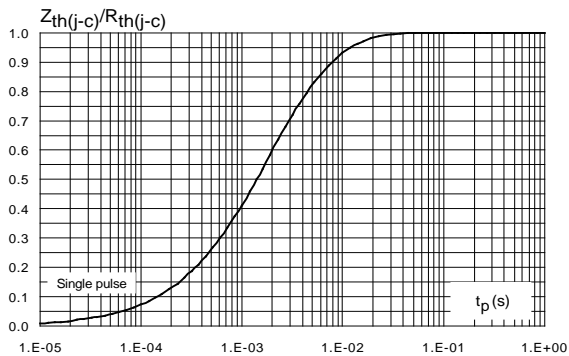
**Figure 3: Peak forward current versus case temperature**



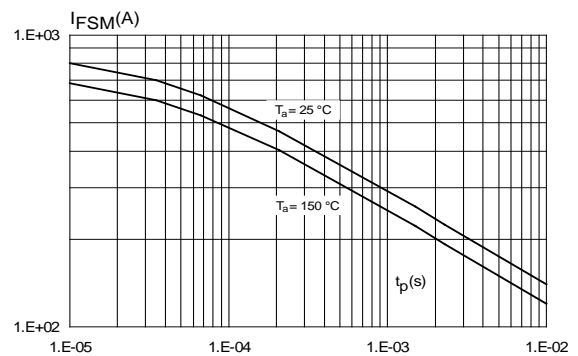
**Figure 4: Junction capacitance versus reverse voltage applied (typical values)**



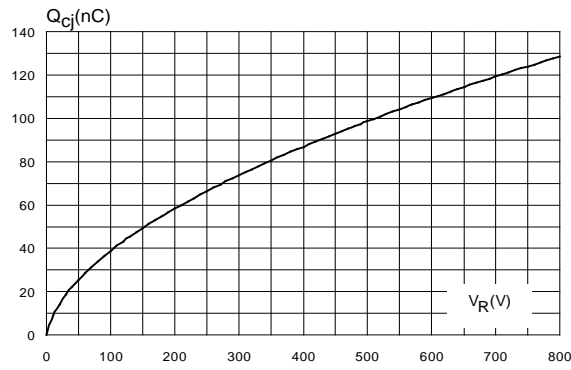
**Figure 5: Relative variation of thermal impedance junction to case versus pulse duration**



**Figure 6: Non-repetitive peak surge forward current versus pulse duration (sinusoidal waveform)**



**Figure 7: Total capacitive charges versus reverse voltage applied (typical values)**



**Figure 8: Thermal resistance junction to ambient versus copper surface under tab for D<sup>2</sup>PAK package (typical values)**

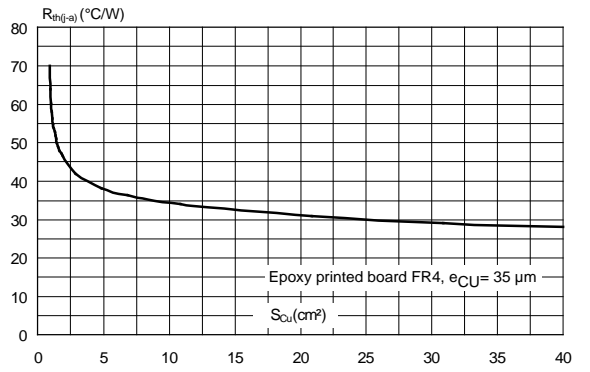




Table 6: TO-220AC package mechanical data

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.173	0.181
C	1.23	1.32	0.048	0.051
D	2.40	2.72	0.094	0.107
E	0.49	0.70	0.019	0.027
F	0.61	0.88	0.024	0.034
F1	1.14	1.70	0.044	0.066
G	4.95	5.15	0.194	0.202
H2	10.00	10.40	0.393	0.409
L2	16.40 typ.		0.645 typ.	
L4	13.00	14.00	0.511	0.551
L5	2.65	2.95	0.104	0.116
L6	15.25	15.75	0.600	0.620
L7	6.20	6.60	0.244	0.259
L9	3.50	3.93	0.137	0.154
M	2.6 typ.		0.102 typ.	
Diam	3.75	3.85	0.147	0.151

## 2.2 D<sup>2</sup>PAK package information

Figure 10: D<sup>2</sup>PAK package outline

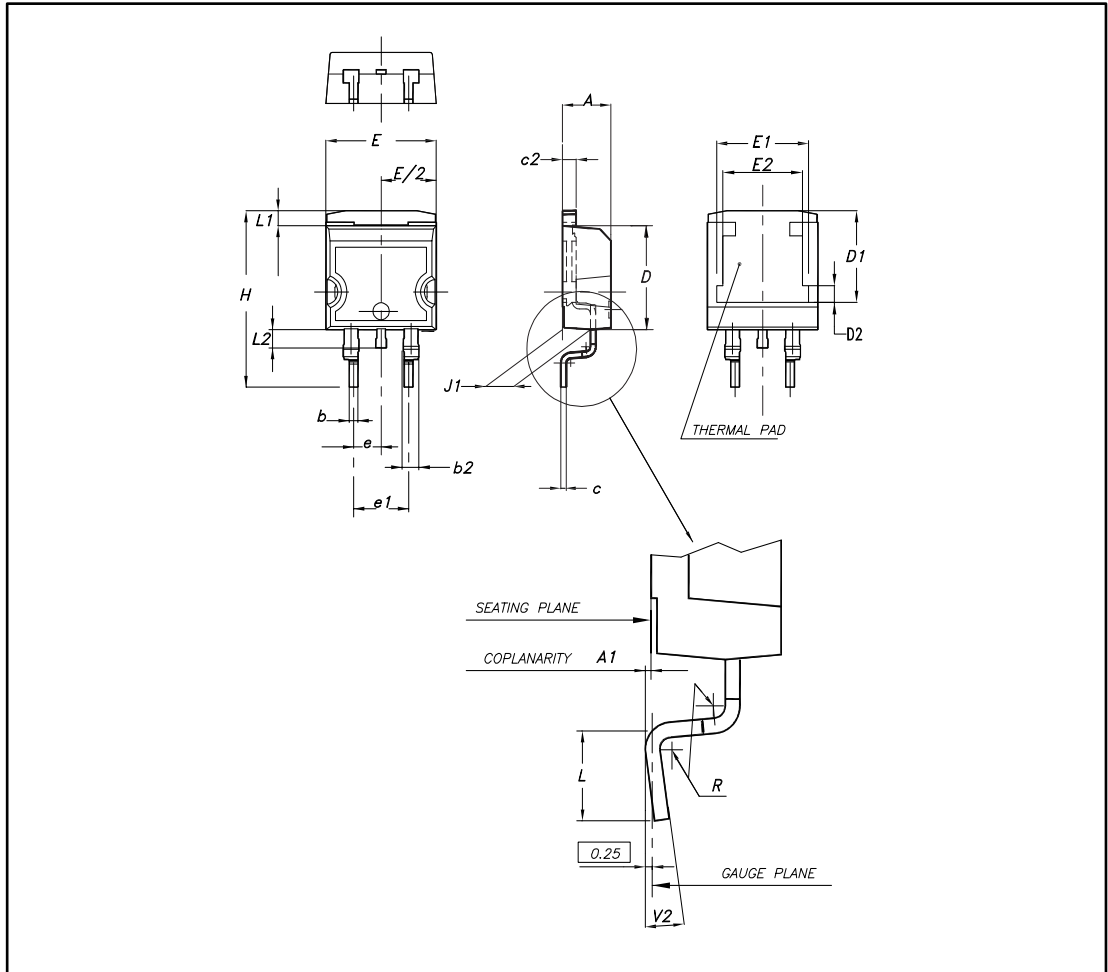
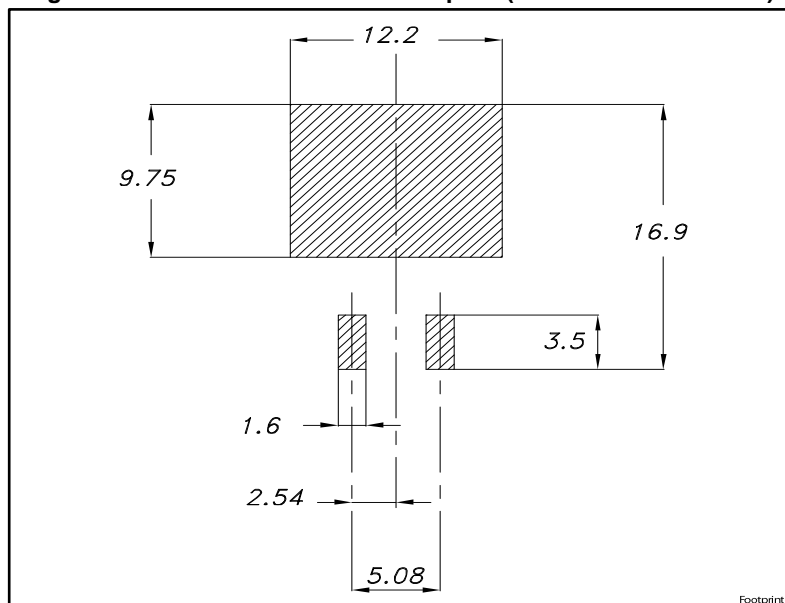


Table 7: D<sup>2</sup>PAK package mechanical data

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.40		4.60	0.173		0.181
A1	0.03		0.23	0.001		0.009
b	0.70		0.93	0.028		0.037
b2	1.14		1.70	0.045		0.067
c	0.45		0.60	0.018		0.024
c2	1.23		1.36	0.048		0.053
D	8.95		9.35	0.352		0.368
D1	7.50	7.75	8.00	0.295	0.305	0.315
D2	1.10	1.30	1.50	0.043	0.051	0.060
E	10		10.40	0.394		0.409
E1	8.50	8.70	8.90	0.335	0.343	0.346
E2	6.85	7.05	7.25	0.266	0.278	0.282
e		2.54			0.100	
e1	4.88		5.28	0.190		0.205
H	15		15.85	0.591		0.624
J1	2.49		2.69	0.097		0.106
L	2.29		2.79	0.090		0.110
L1	1.27		1.40	0.049		0.055
L2	1.30		1.75	0.050		0.069
R		0.4			0.015	
V2	0°		8°	0°		8°

Figure 11: D<sup>2</sup>PAK recommended footprint (dimensions are in mm)





### 3 Ordering information

Table 8: Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STPSC20H12D	STPSC20H12D	TO-220AC	1.86 g	50	Tube
STPSC20H12G-TR	STPSC20H12G	D <sup>2</sup> PAK	1.48 g	1000	Tape and reel

### 4 Revision history

Table 9: Document revision history

Date	Revision	Changes
13-May-2016	1	Initial release.
26-May-2016	2	Updated <i>Table 2: "Absolute ratings (limiting values at 25 °C, unless otherwise specified)"</i> and <i>Figure 6: "Non-repetitive peak surge forward current versus pulse duration (sinusoidal waveform)"</i> .
10-Apr-2017	3	Added D <sup>2</sup> PAK package.

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